

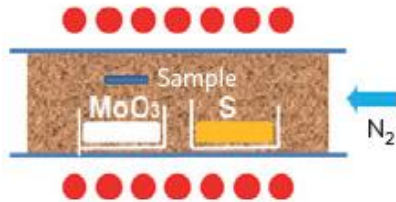
Layer-modulated synthesis of uniform tungsten disulfide nanosheet using gas-phase precursors.

Jusang Park* Hyungjun Kim

School of Electrical and Electronics Engineering,
Yonsei University, 262 Seongsanno, Seodaemun-gu,
Seoul, Korea

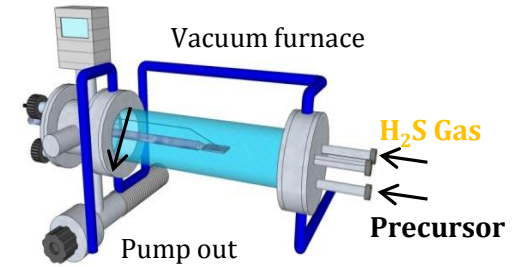
Growth of CVD WS₂

<Previous CVD method>



Lee Y-H et al, *Adv. Mater*, 24, 2320-2325, (2012)

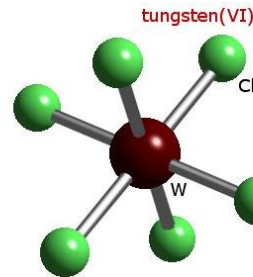
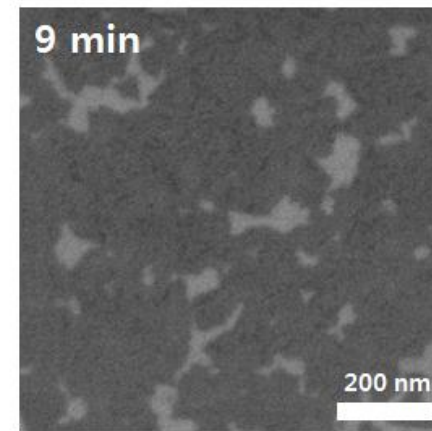
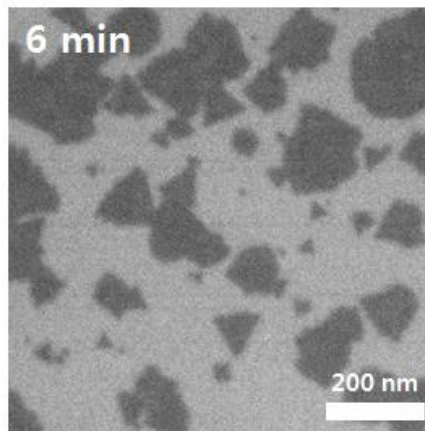
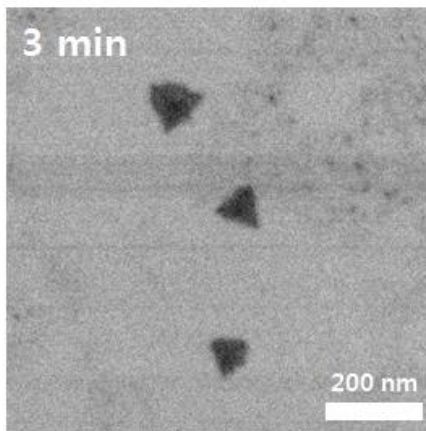
<Gas Phase CVD WS₂>



Tube furnace

Growth temperature : 700 °C

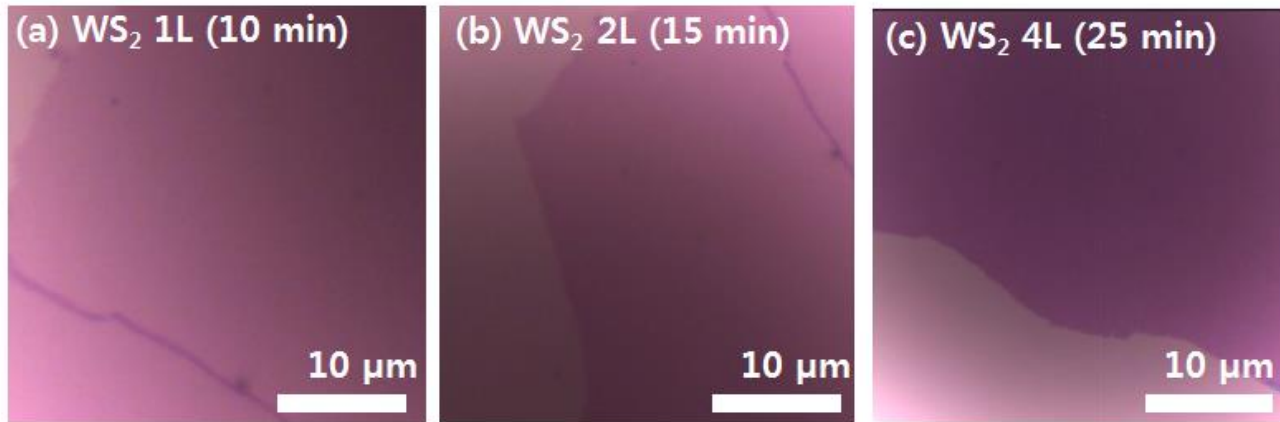
<SEM>



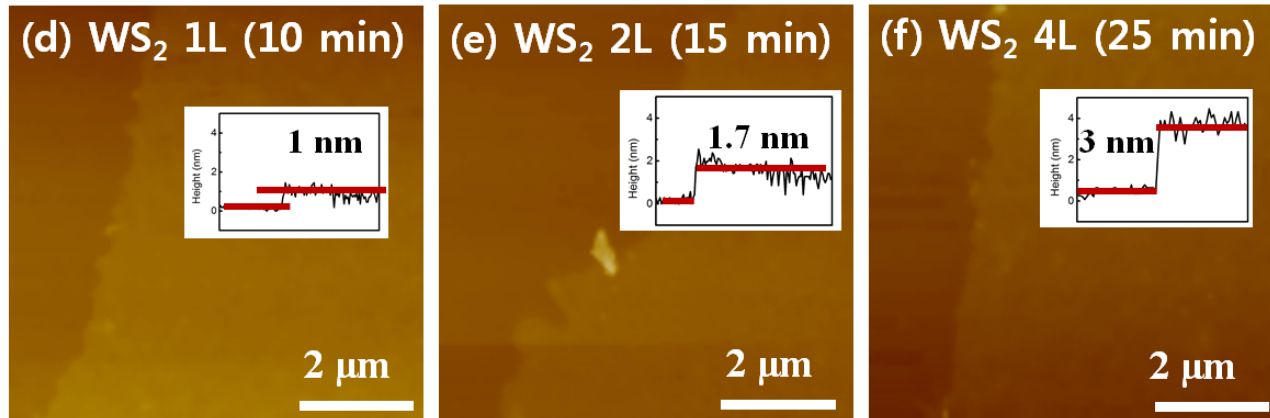
- Initial growth of CVD WS₂ → Time dependent lateral growth of WS₂

Time dependent Layer Control

<Optical Microscopy>

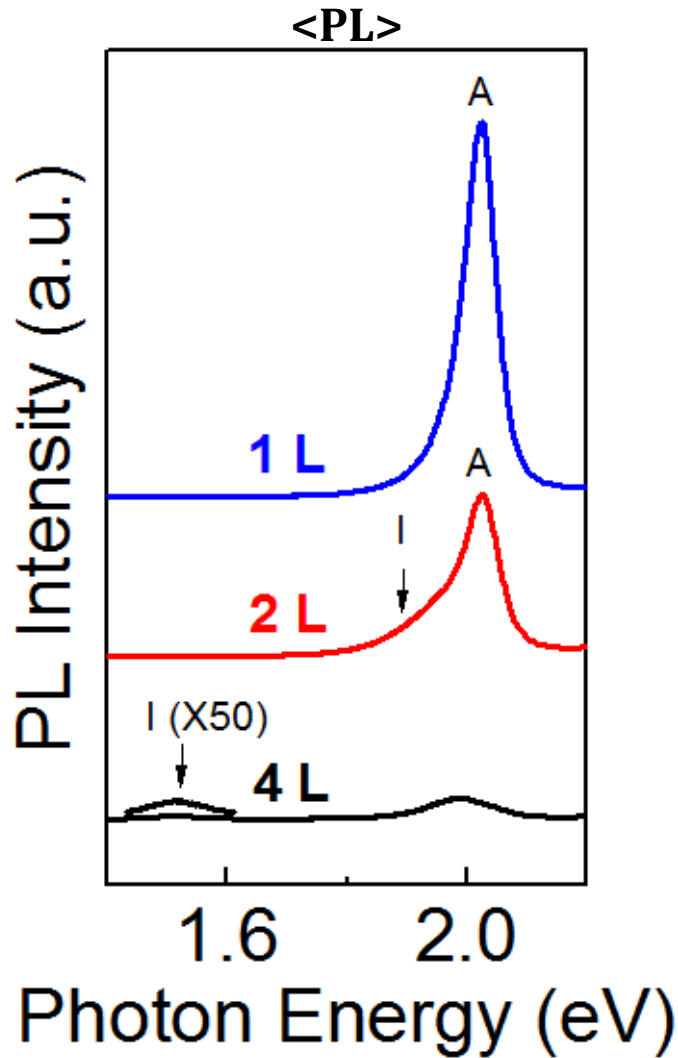


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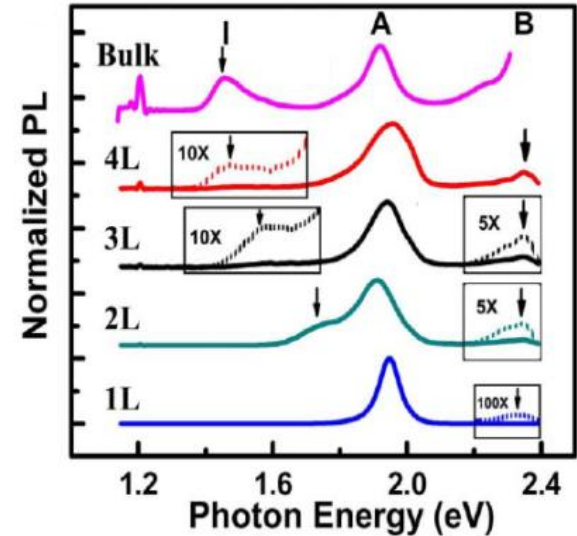


- Number of layer dependent on the cycle number of ALD WO₃

Optical Property of CVD WS₂



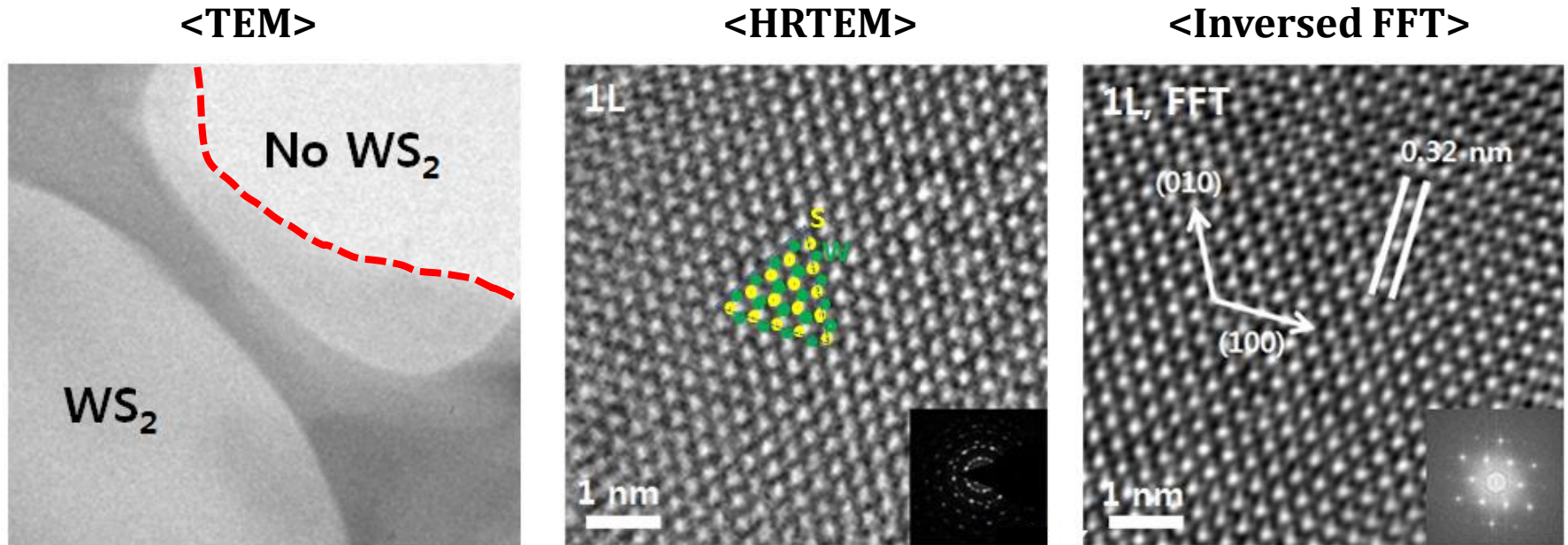
<Electronic structure of WS₂>



Zeng, H. et al, *Sci, Rep.* 3, 1608, (2013)

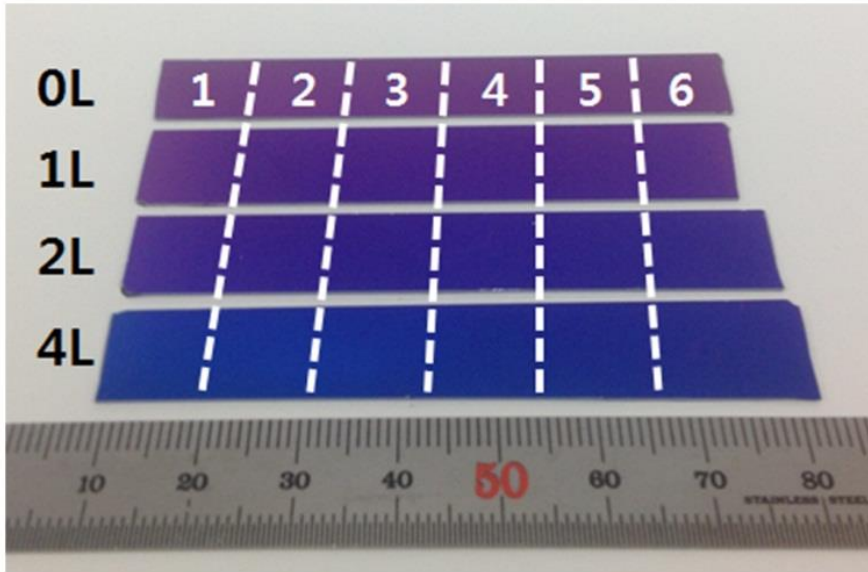
- PL spectra for the 1L, 2L and 4L WS₂ nanosheets
 - Indirect to direct band gap transition with reducing number of layer
 - I peak from PL spectrum of 2L and 4L WS₂

Atomic Arrangement of CVD WS₂

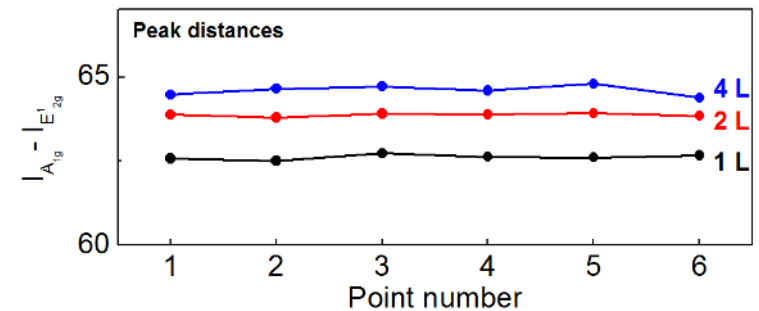
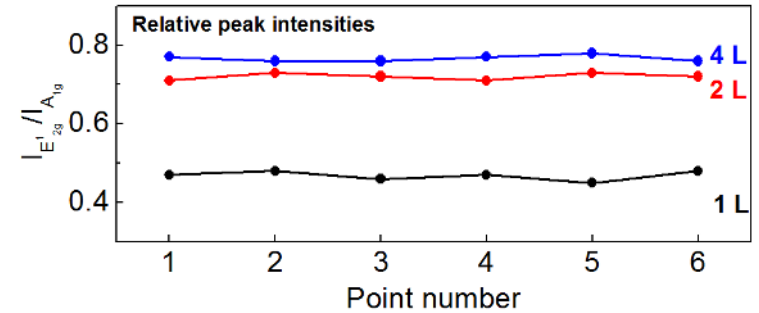


- Low-magnification TEM image for a 1L WS₂ nanosheet on a TEM grid
- HRTEM image of 1L WS₂ nanosheet at a selected region and (inset) the SAED pattern
- Inverse FFT by applying a mask
 - (100) and (110) crystal directions
 - Lattice spacing: 0.26 nm and 0.16 nm for the (100) and (110) planes

Large Area Uniformity of CVD WS₂



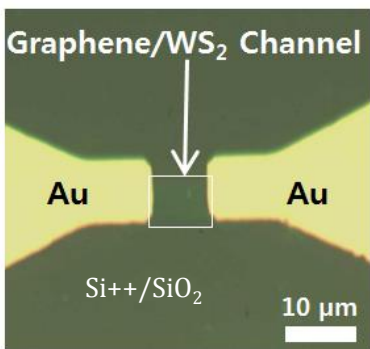
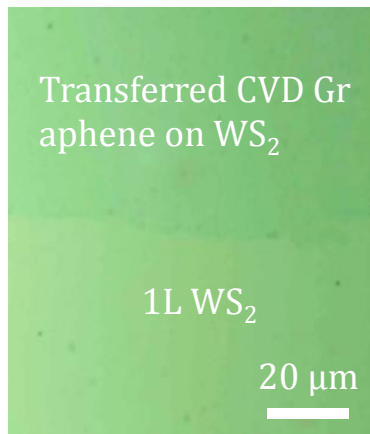
<Raman analysis>



- Color dependency on the number of layers
- Large-area uniformity on 1 cm X 7 cm SiO₂

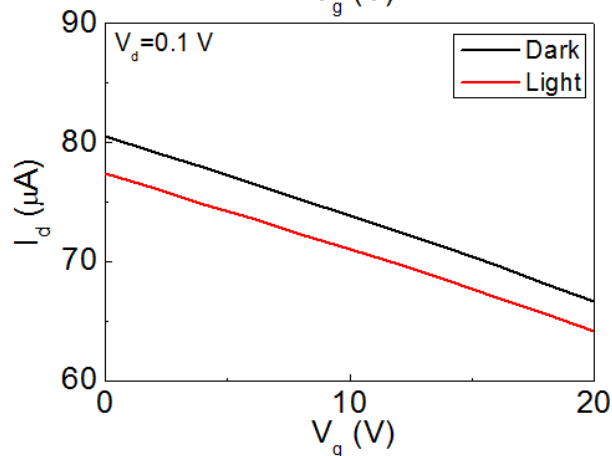
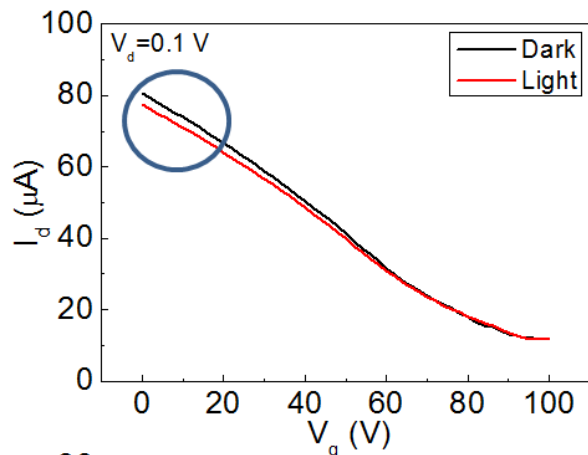
Graphene/WS₂ Photo-Detector

<OM image>

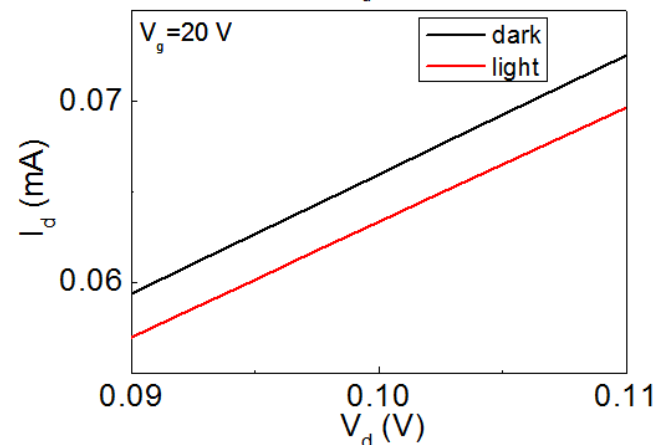
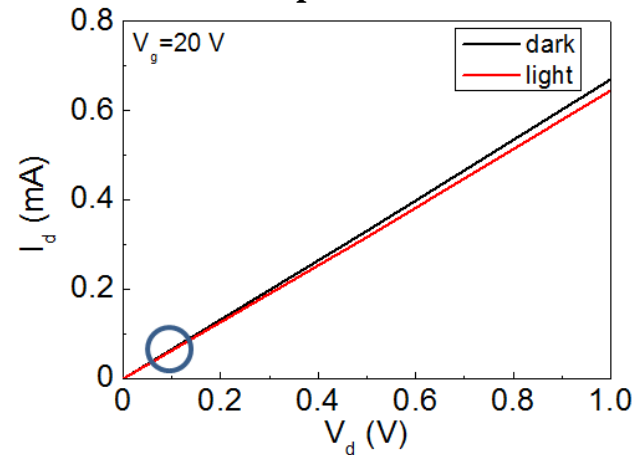


Unpublished Data

<Transfer curve>



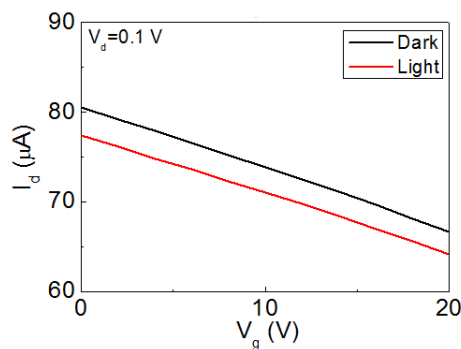
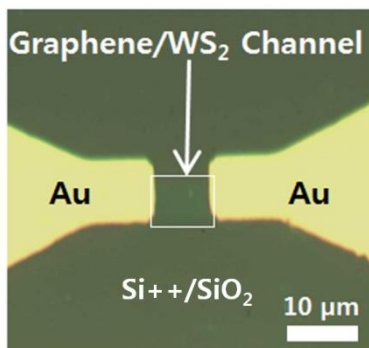
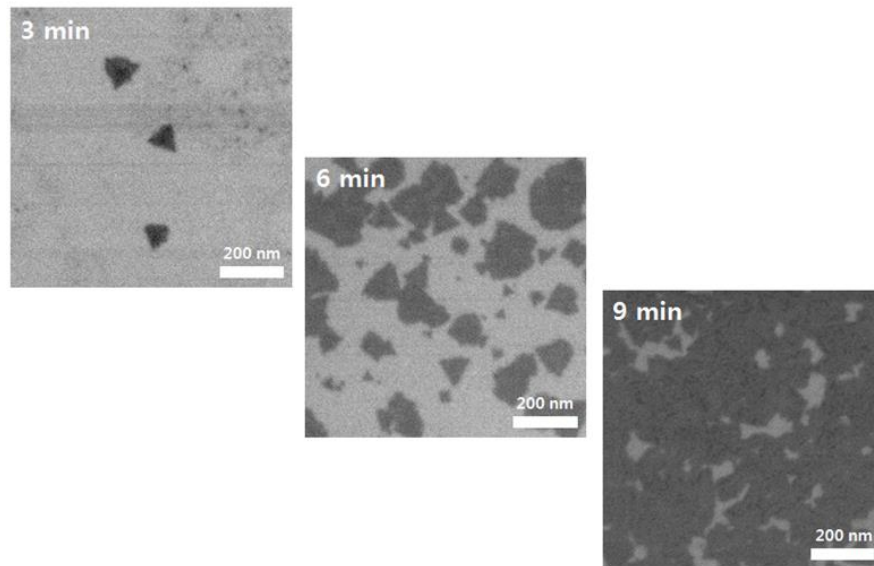
<Output curve>



- $\Delta I_d / I_d @ V_g = 0 \text{ V} \rightarrow 4\%$ with monochromatic green light ($\sim 550 \text{ nm}$) @ 1 W/m^2
- Lower than exfoliated few-layer MoS₂ with CVD graphene photo-detector ($\sim 7\%$ @ 0.6 W/m^2)

Summary

- CVD WS_2 nanosheets are synthesized using gas phase S reactant
- Lateral growth and coalescence of two or more domains are observed
- Number of layer can be controlled by reaction time

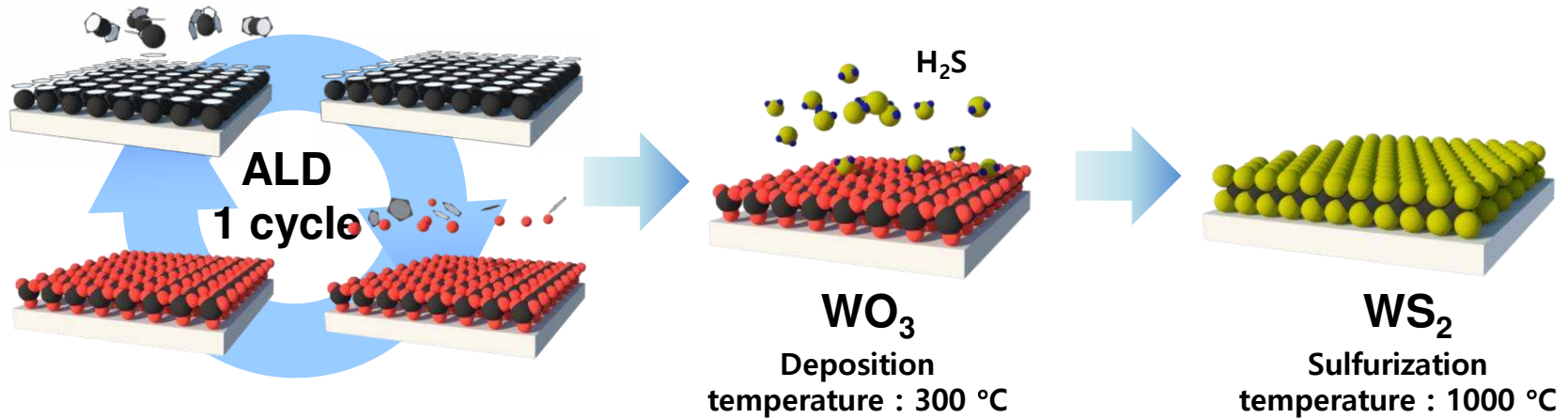


- Graphene/ WS_2 hetero-structure shows properties of photo detecting

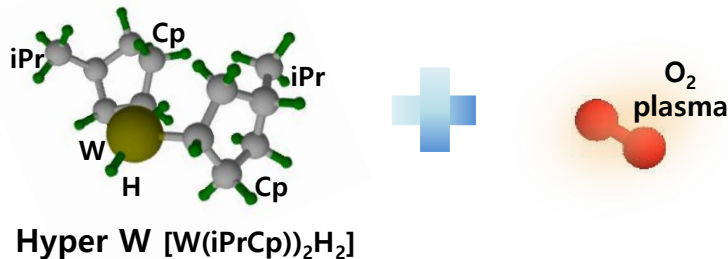
Synthesis of TMDCs nanosheet
Based on Atomic Layer Deposition
(Metal Oxide Sulfurization)

Synthesis of WS₂ Nanosheets Using ALD

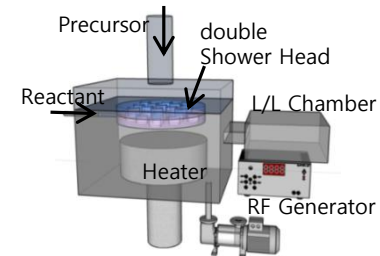
<Procedure of ALD based WS₂ nanosheets synthesis>



<Precursor and Reactant for ALD WO₃>

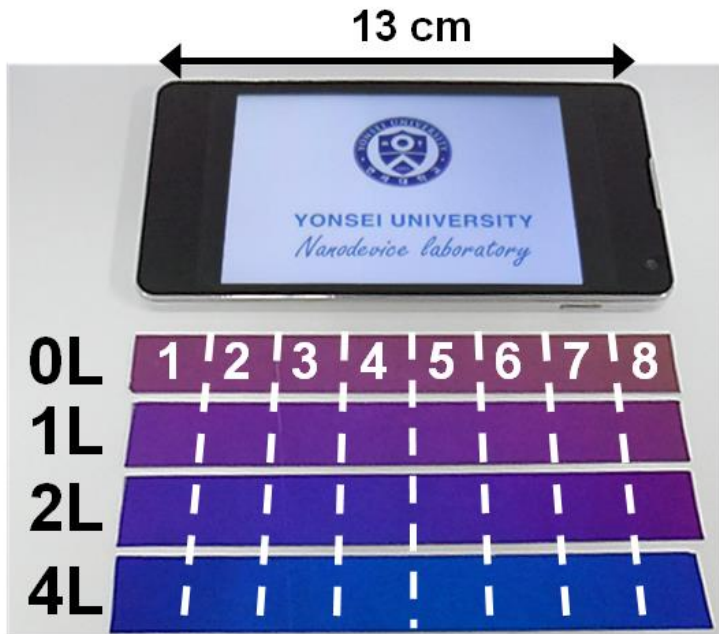


<Shower head type 6 inch ALD>

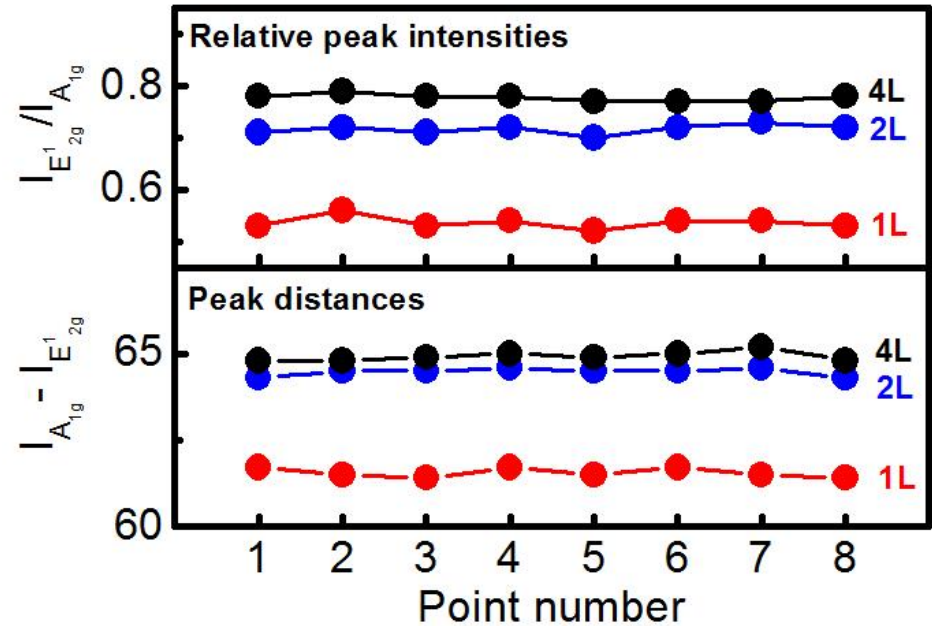


- Hyper W and O₂ plasma as precursor and reactant for ALD WO₃
- Shower head type 6" ALD plasma reactor for ALD WO₃

Wafer-Scale Uniformity of WS₂



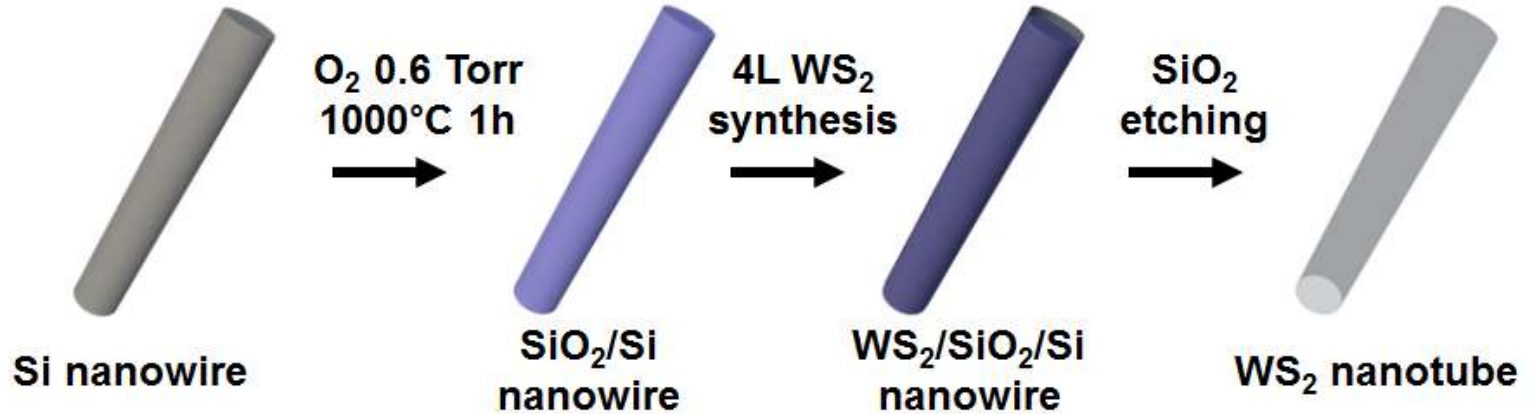
<Raman analysis>



- Large area (approximately 13 cm) 1L, 2L and 4L WS₂ nanosheets
- Relative Raman peak intensities and peak distances of the E_{2g}¹ and A_{1g} modes for eight measurement points on large area WS₂ nanosheets

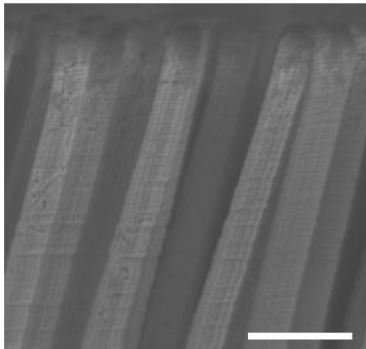
WS₂ Nanotubes Fabrication

<Synthesis procedure of WS₂ nanotubes>

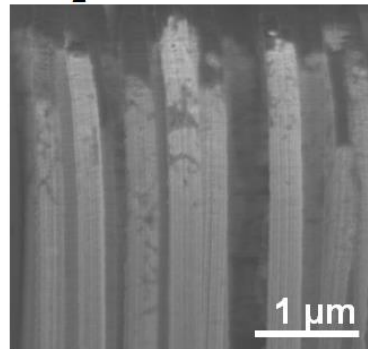


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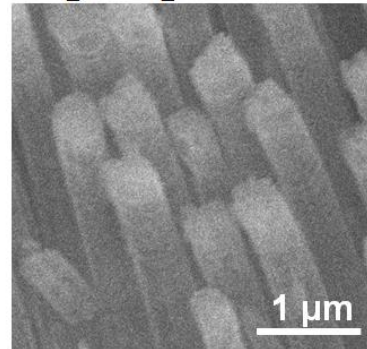
Si NWs



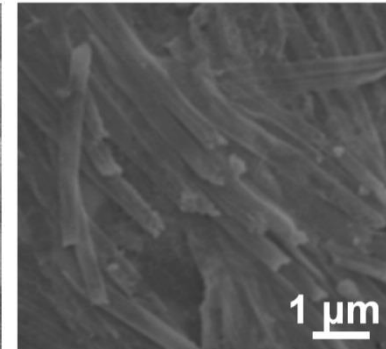
SiO₂/Si NWs



WS₂/SiO₂/Si NWs

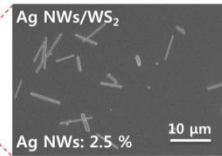
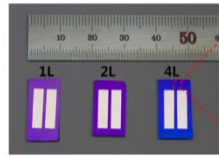


WNTs

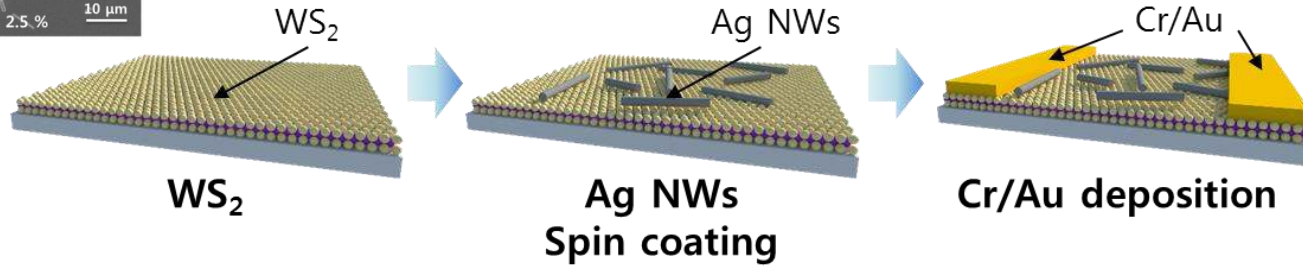


- Conformality of ALD
→ Fabrication of WS₂ nanotubes using ALD based WS₂ proc

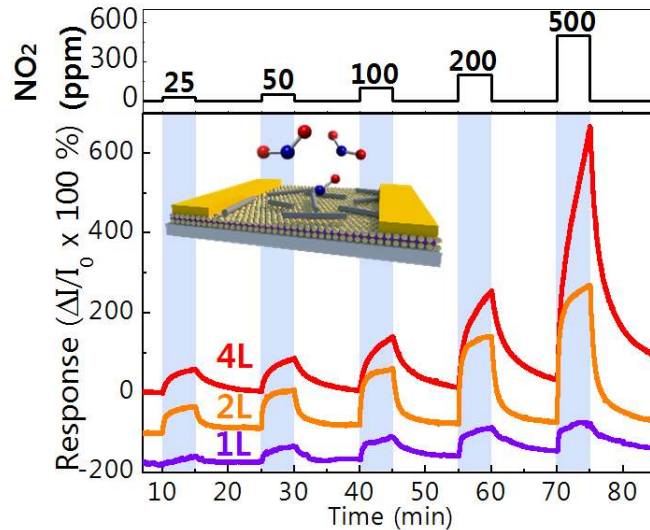
Gas Sensing Properties of WS₂



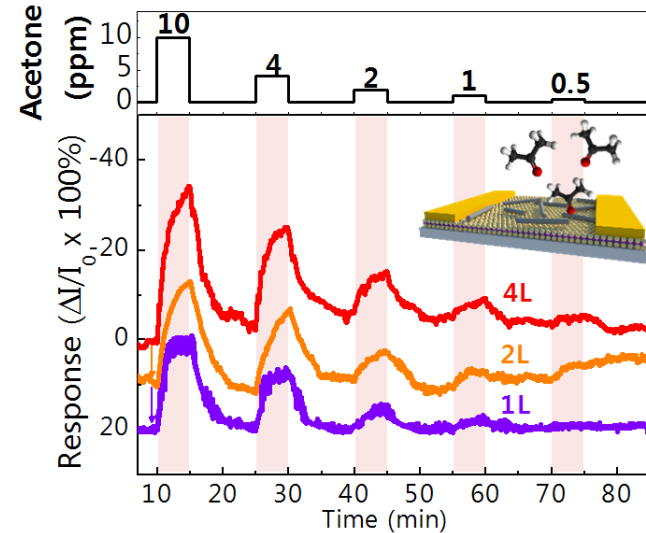
<Functionalization of WS₂>



<NO₂ Gas Sensing>

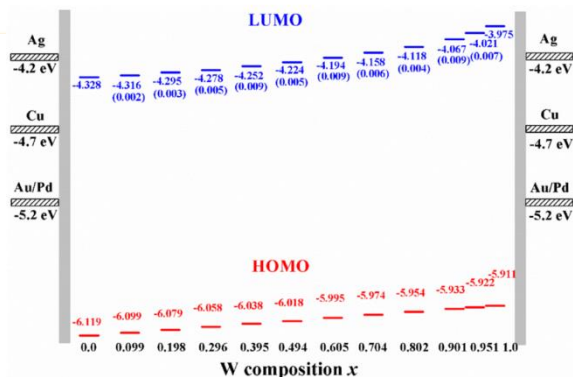
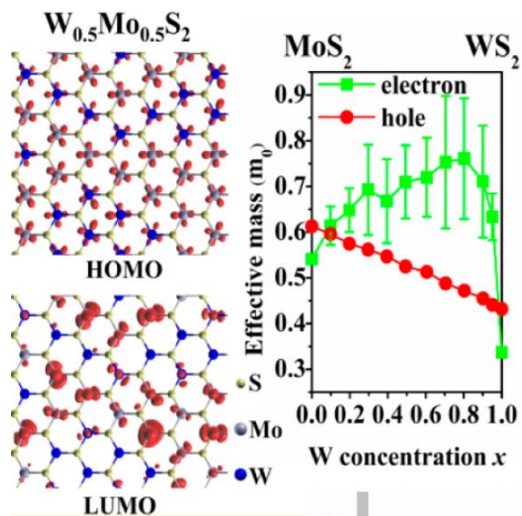


<Acetone Gas Sensing>

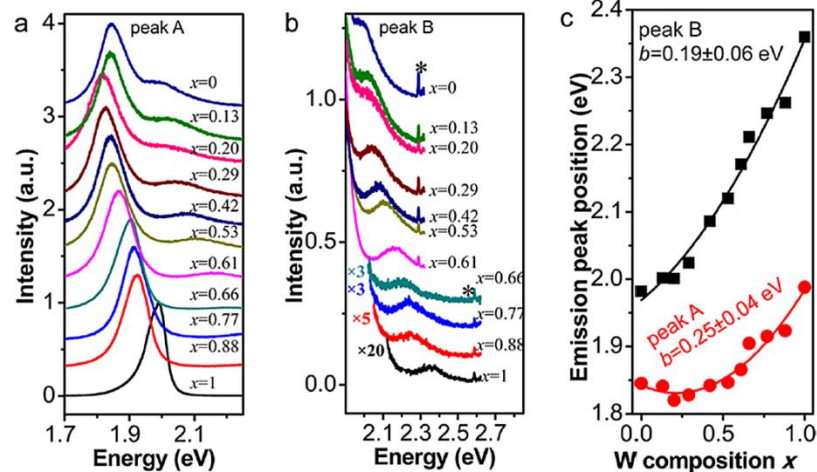
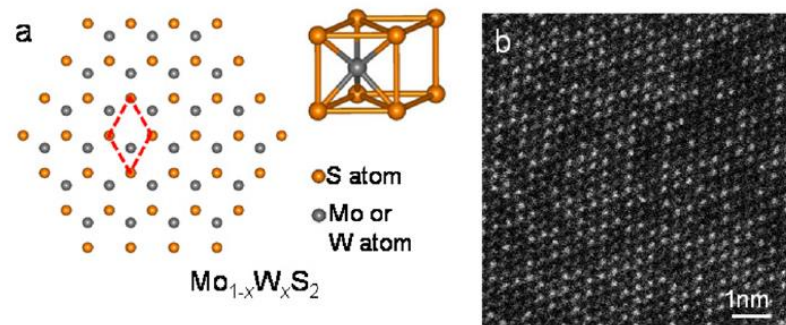


- Highly enhanced response to NO₂ → 12 times enhanced compared to pristine

Mo_(1-x)W_xS₂ Nanosheets



Jinyang Xi et al, *Jour of Phy. Chem. Lett*, 5, 285–291, (2014)

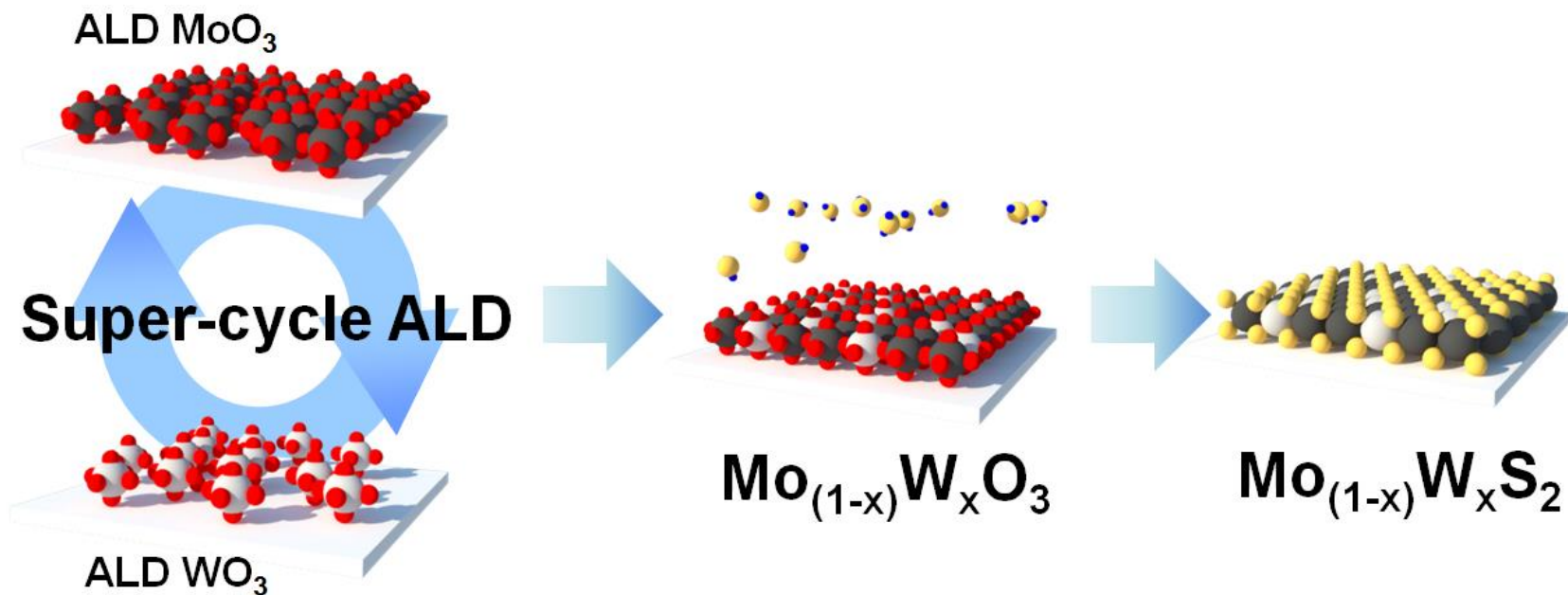


Yanfeng Chen et al, *ACS Nano*, 7(5), 4610–4616, (2013)

- 2D $Mo_{(1-x)}W_xS_2$ nanosheets
 → Thermally stable, tunable band gap with control of composition ratio
- No report on synthesis of 2D $Mo_{(1-x)}W_xS_2$ alloy nanosheet

Synthesis of $\text{Mo}_{(1-x)}\text{W}_x\text{S}_2$ Nanosheets

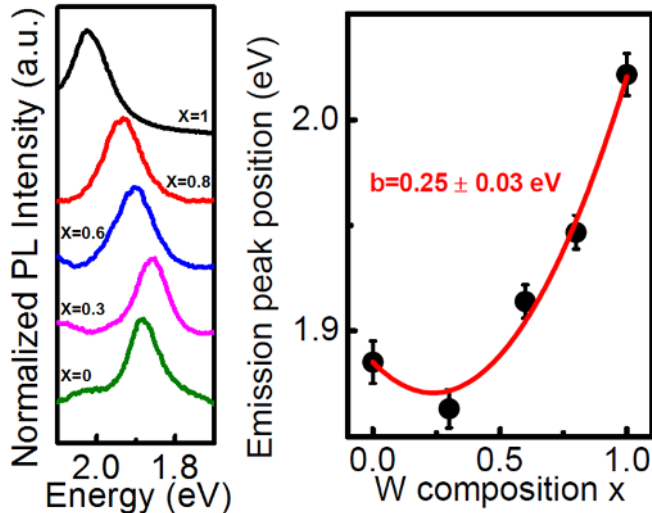
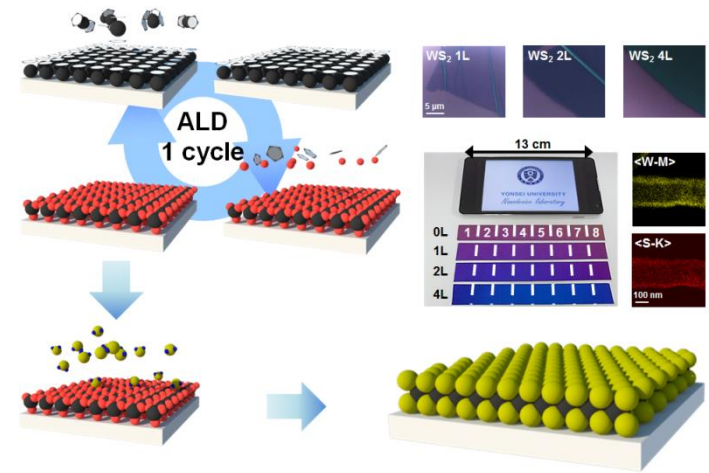
<Synthesis procedure of ALD based $\text{Mo}_{(1-x)}\text{W}_x\text{S}_2$ nanosheets>



- Sulfurization of $\text{Mo}_{(1-x)}\text{W}_x\text{O}_3$ thin films deposited by super-cycle of PE-ALD
- Depending on the cycle ratio of MoO_3 and WO_3 , contents ratio of Mo and W can be controlled

Summary

- ALD based WS_2 nanosheets show several advantages of ALD
 - Atomic scale thickness control,
 - Wafer-scale uniformity,
 - Conformality

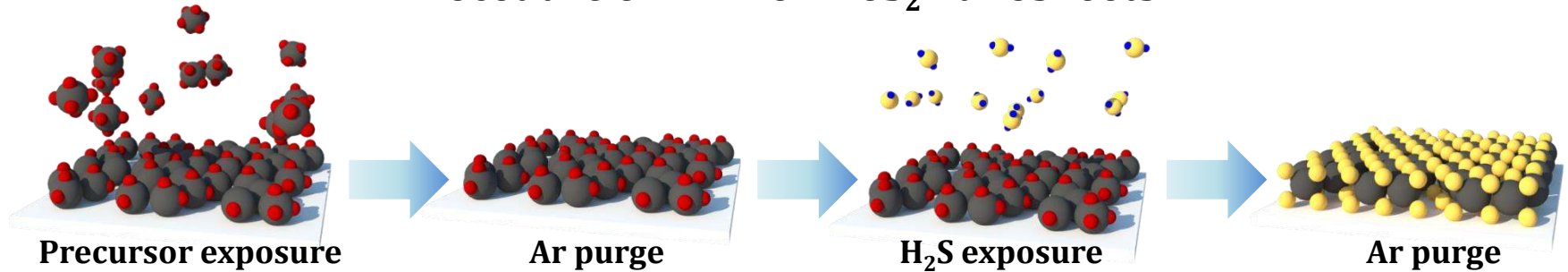


- Super-cycle ALD can be possible tuning of band gap of 2D TMDCs nanosheets by synthesis of $\text{Mo}_{(1-x)}\text{W}_x\text{S}_2$ alloy and vertical composition-controlled $\text{Mo}_{(1-x)}\text{W}_x\text{S}_2$

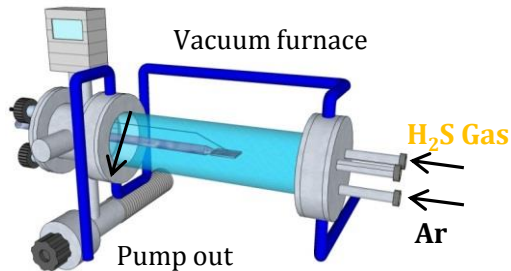
Synthesis of MoS₂ nanosheet
Based on Atomic Layer Deposition
(Direct Synthesis)

Synthesis of MoS₂ Nanosheets

<Procedure of ALD for MoS₂ nanosheets>

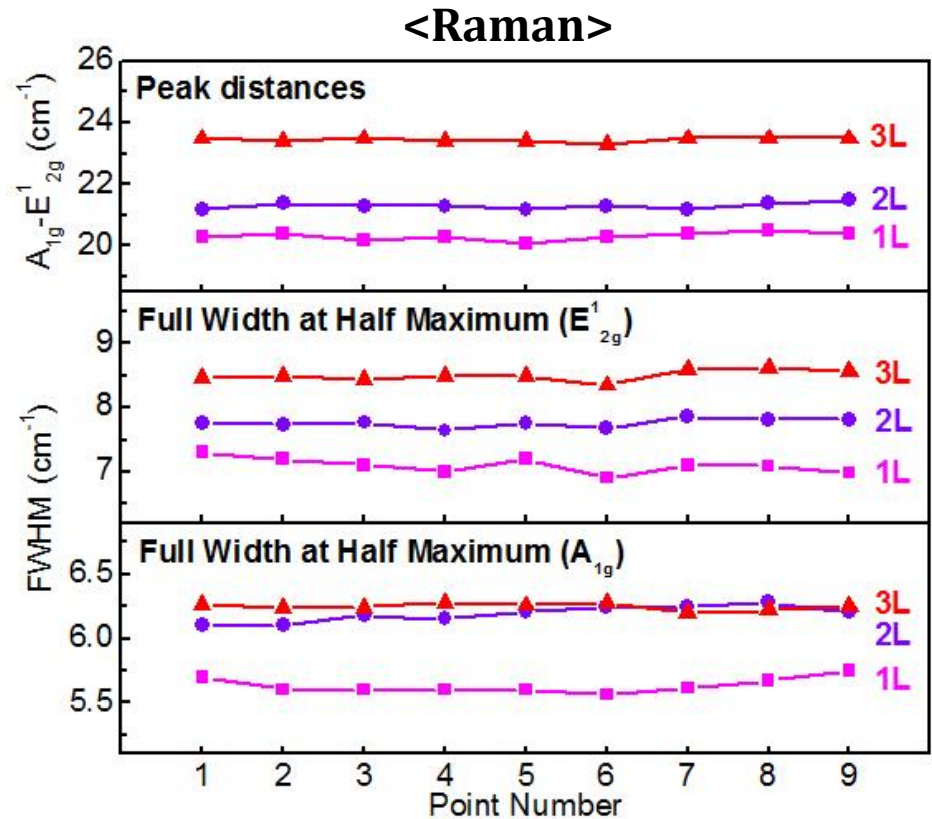
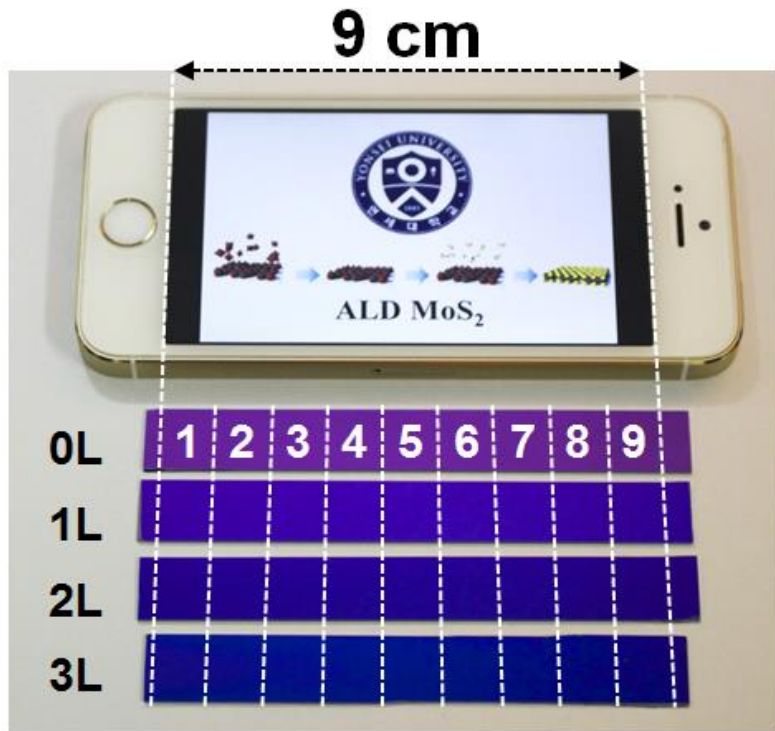


<Equipment for ALD>



- Gas phase H₂S is employed as the reactant in ALD MoS₂ process
- Tube type furnace ALD reactor for MoS₂

Wafer-Scale Uniformity of MoS₂

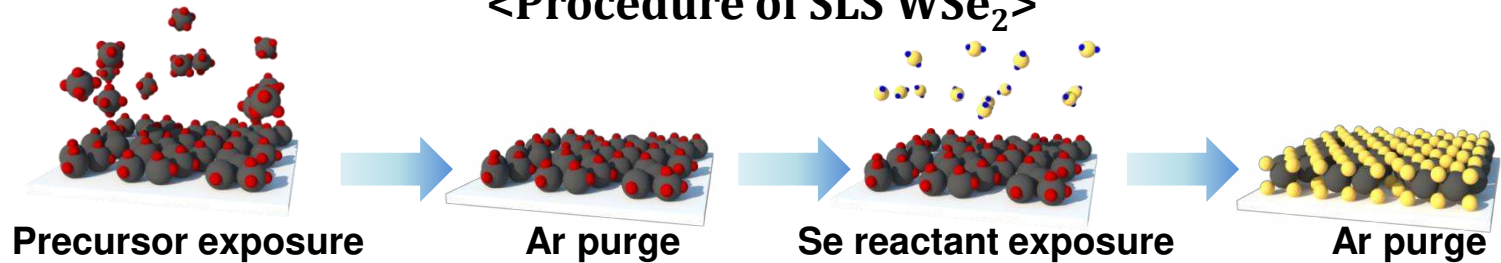


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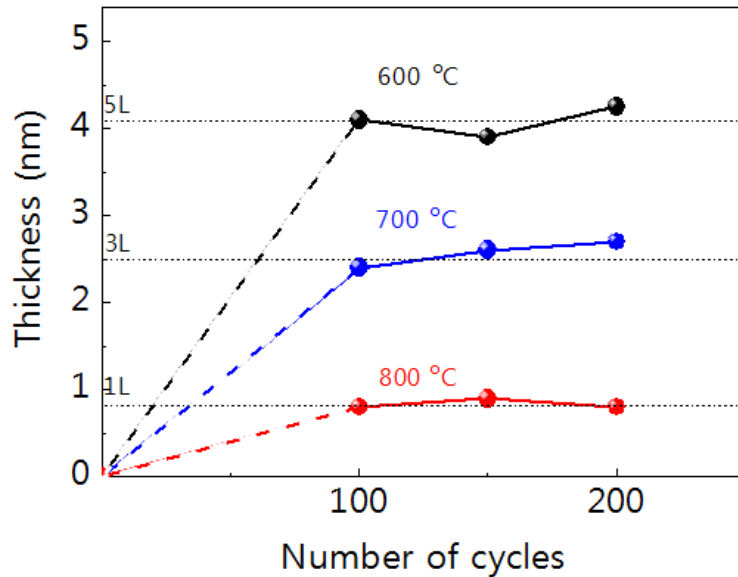
- Large area (approximately 9 cm) 1L, 2L and 3L MoS₂ nanosheets
 - Relative Raman peak distances and FWHM for E_{2g}^1 and A_{1g} modes for nine measurement points on large area MoS₂ nanosheets
 - Results show small variation for the nine points
- good thickness uniformity over wafer-scale

SLS WSe₂

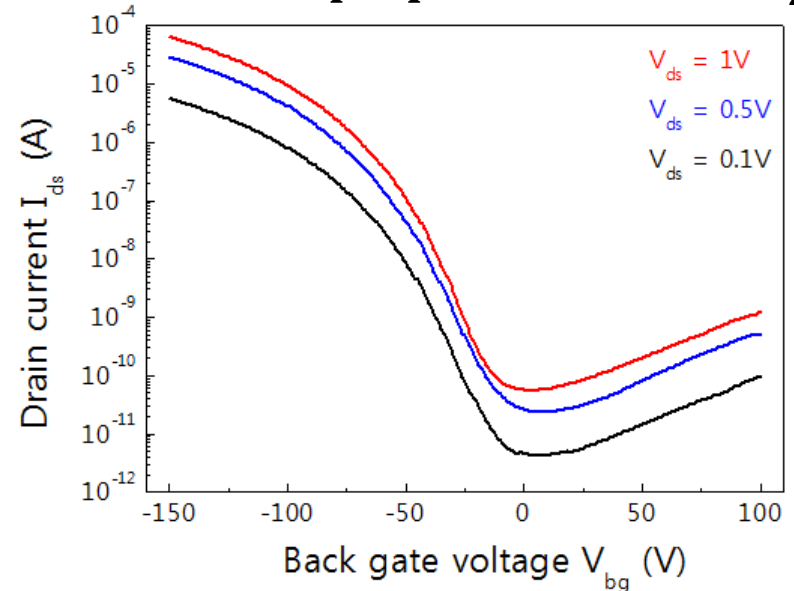
<Procedure of SLS WSe₂>



<Self-limiting Layer Synthesis>

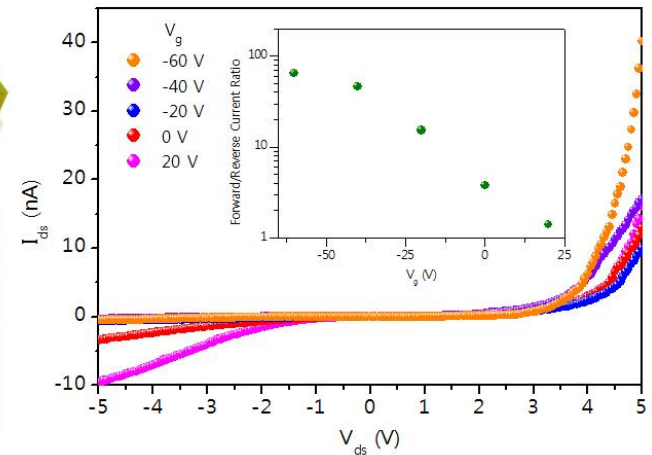
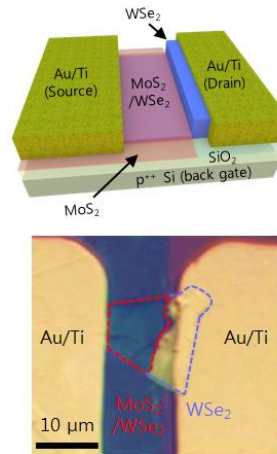
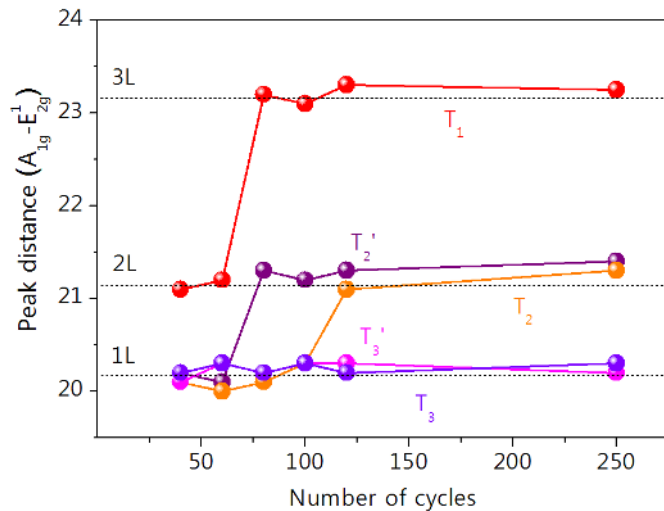
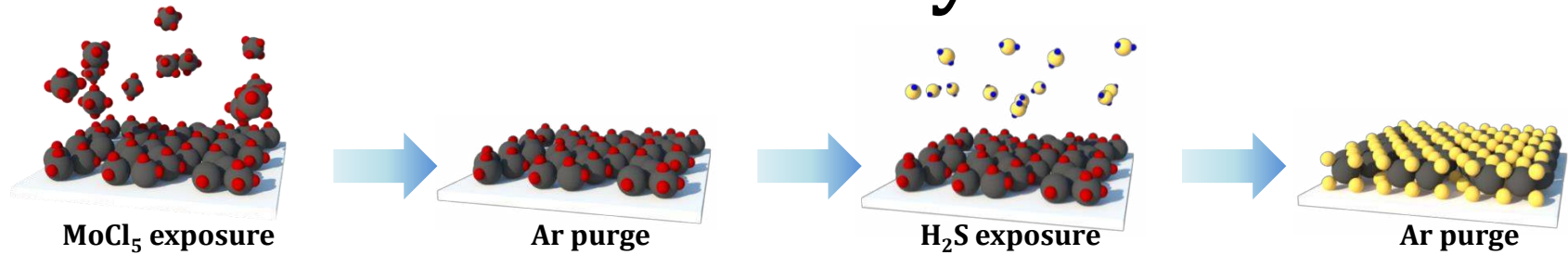


<Electrical properties of 3L WSe₂>



- Preserving self-limiting layer synthesis characteristics for WSe₂
→ Universally applicable to synthesize 2D TMDCs
- 3L WSe₂ → p-type behavior with mobility = 2.2 cm²/Vs, on/off ratio = 10⁶

Summary



- **Synthesis of MoS₂ nanosheet using ALD procedure**
 - Show self-limiting growth behavior (self-limiting layer synthesis, SLS)
- **SLS MoS₂ shows wafer-scale thickness uniformity and layer controllability**
- **SLS MoS₂ valid on WSe₂ surface → feasible for 2D TMDCs heterostructure**